UNITED STATES PATENT AND TRADEMARK OFFICE

# CERTIFICATE OF CORRECTION

PATENT NO. : 6,958,511 B1
DATED : October 25, 2005
INVENTOR(S) : Halliyal et al.



It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

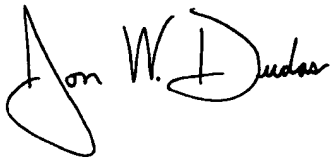
Title page,
Item [56], **References Cited**, insert:
-- FOREIGN PATENT DOCUMENTS
JP-A 1032001740 --.

Column 8,
Line 37, replace "insulator (SOD semiconductor" with -- insulator (SOI) semiconductor --.

Column 18,
Line 6, replace "a fist region" with -- a first region --.
Line 28, replace "claim B, wherein" with -- claim 8, wherein --.
Line 52, replace "about 20 percent." with -- about 20 atomic percent. --.

Signed and Sealed this

Seventeenth Day of January, 2006



JON W. DUDAS
*Director of the United States Patent and Trademark Office*